## NSN 5962-01-078-5467

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-078-5467 **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 550.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** E3a acft **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs and bipolar and low power and schottky **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-2 mil-m-38510 **Current Rating Per Characteristic:** 105.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds delay **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 printed circuit

N/a

Shelf Life:

## NSN 5962-01-078-5467

Memory Microcircuit - Page 2 of 2



	1	:.	~	84				
ι	JN	IT	UΤ	IVI	ea	Sι	ire:	•

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0